

RoHS

HALOGEN

FREE

1 pC Charge Injection, 100 pA Leakage, Quad SPST Switches

DESCRIPTION

The DG611A, DG612A and DG613A contain independently selectable SPST switches. They offer improved performance over the industry standard DG611 series. The DG611A and DG612A have all switches normally closed and normally open respectively, while the DG613A has 2 normally open and 2 normally closed switches.

They are designed to operate from a 2.7 V to 12 V single supply or from \pm 2.7 V to \pm 5 V dual supplies and are fully specified at +3 V, +5 V and $\pm 5 \text{ V}$. All control logic inputs have guaranteed 2 V logic high limits when operating from + 5 V or \pm 5 V supplies and 1.4 V when operating from a \pm 3 V supply. The DG611A, DG612A and DG613A switches conduct equally well in both directions and offer rail to rail analog signal handling.

1 pC low charge injection, coupled with very low switch capacitance: 2 pF, fast switching speed: ton/toff 27 ns/16 ns and excellent 3 dB bandwidth: 720 MHz, make these products ideal for precision instrumentation, high-end data acquisition, automated test equipment and high speed communication applications.

Operation temperature is specified from - 40 °C to + 125 °C. The DG611A, DG612A and DG613A are available in 16 lead SOIC, TSSOP and the space saving 1.8 mm x 2.6 mm miniQFN packages.

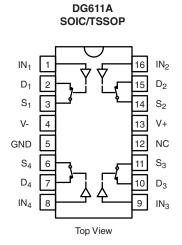
FEATURES

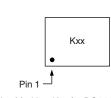
- Halogen-free according to IEC 61249-2-21 **Definition**
- Low charge injection (1 pC typ.)
- Leakage current < 0.25 nA at 85 °C
- Low switch capacitance (C_{soff} 2 pF typ.)
- Low $R_{DS(on)}$ 115 Ω max.
- Fully specified with single supply operation at 3 V, 5 V and dual supplies at \pm 5 V
- Low voltage, 2.5 V CMOS/TTL compatible
- 720 MHz, 3 dB bandwidth
- Excellent isolation performance (62 dB at 10 MHz)
- Excellent crosstalk performance (90 dB at 10 MHz)
- Fully specified from 40 °C to + 85 °C and 40 °C to + 125 °C
- 16 lead SOIC, TSSOP and miniQFN package (1.8 mm x 2.6 mm)
- Compliant to RoHS Directive 2002/95/EC

APPLICATIONS

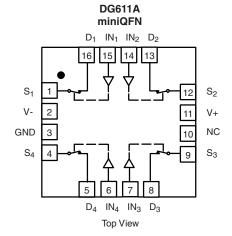
- Precision instrumentation
- Medical instrumentation
- Automated test equipment
- High speed communications applications
- High-end data acquisition
- Sample and hold applications
- Sample and hold systems

FUNCTIONAL BLOCK DIAGRAM AND PIN CONFIGURATION





Device Marking: Kxx for DG611A Lxx for DG612A (miniQFN16) Pxx for DG613A xx = Date/Lot Traceability Code

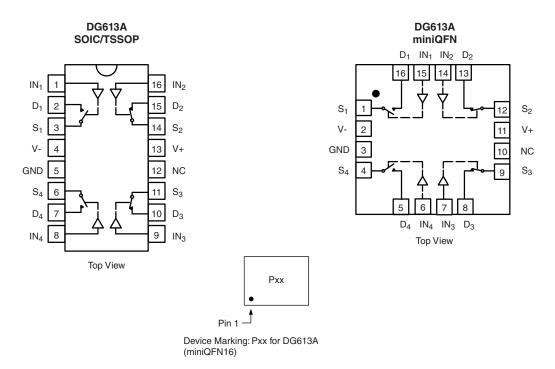


TRUTH TABLE						
Logic	DG611A	DG612A				
0	On	Off				
1	Off	On				

Document Number: 69904 S11-1066-Rev. C, 30-May-11



FUNCTIONAL BLOCK DIAGRAM AND PIN CONFIGURATION



TRUTH TABLE							
Logic	SW ₁ , SW ₄	SW_2, SW_3					
0	Off	On					
1	On	Off					

ORDERING INFORMATION								
Temp. Range	Package	Part Number						
DG611A, DG612A, DG613A								
	16-pin TSSOP	DG611AEQ-T1-E3 DG612AEQ-T1-E3						
	10 piii 10001	DG613AEQ-T1-E3						
- 40 °C to 125 °C ^a	16-pin Narrow SOIC	DG611AEY-T1-E3 DG612AEY-T1-E3						
	·	DG613AEY-T1-E3						
		DG611AEN-T1-E4						
	16-pin miniQFN	DG612AEN-T1-E4 DG613AEN-T1-E4						

Notes:

a. - 40 °C to 85 °C datasheet limits apply.





ABSOLUTE MAXIMUM RATINGS (T _A = 25 °C, unless otherwise noted)						
Parameter		Limit	Unit			
V + to V -		14				
GND to V -		7	V			
Digital Inputs ^a , V _S , V _D		(V -) - 0.3 V to (V +) + 0.3 V or 30 mA, whichever occurs first				
Continuous Current (Any Terminal)		30	mA			
Peak Current, S or D (Pulsed 1 ms, 10 %	6 Duty Cycle)	100	- IIIA			
Storage Temperature		- 65 to 150	°C			
	16-pin TSSOP ^c	450				
Power Dissipation (Package) ^b	16-pin miniQFN ^d	525	mW			
	16-pin Narrow SOIC ^e	640				
	16-pin TSSOP	178				
Thermal Resistance (Package) ^b	16-pin miniQFN	152	°C/W			
	16-pin Narrow SOIC	125				

- a. Signals on SX, DX, or INX exceeding V + or V will be clamped by internal diodes. Limit forward diode current to maximum current ratings.
- b. All leads welded or soldered to PC Board.
- c. Derate 5.6 mW/°C above 70 °C.
- d. Derate 6.6 mW/°C above 70 °C.
- e. Derate 8 mW/°C above 70 °C.
- f. Manual soldering with iron is not recommended for leadless components. The miniQFN-16 is a leadless package. The end of the lead terminal is exposed copper (not plated) as a result of the singulation process in manufacturing. A solder fillet at the exposed copper lip cannot be guaranteed and is not required to ensure adequate bottom side solder interconnection.

DG611A, DG612A, DG613A

Vishay Siliconix



OI LOII IOATIONO	FOR DU	JAL SUPPLIES (V $+ = +5$)	V, V - = -	- 5 V)					
		Test Conditions Unless Otherwise Specified			- 40 °C t	o 125 °C	- 40 °C	to 85 °C	<u>; </u>
Dawamatan	Council at	V + = + 5 V, V - = -5 V	T b	T C	Min. ^d	Max. ^d	Min. ^d	Max. ^d	11
Parameter Analog Switch	Symbol	V _{IN} = 2 V, 0.8 V ^a	Temp.b	Typ. ^c	Win."	wax.	Min.	wax.	Unit
Analog Switch Analog Signal Range ^e	V _{ANALOG}		Full		- 5	5	- 5	5	V
			Room	72	- 3	115	- 3	115	· •
On-Resistance	R _{ON}	$I_S = 1 \text{ mA}, V_D = -3 \text{ V}, 0 \text{ V}, +3 \text{ V}$	Full	, _		160		140	
On-Resistance Match	ΔR_{ON}	$I_{S} = 1 \text{ mA}, V_{D} = \pm 3 \text{ V}$	Room Full	0.7		4 6.5		4 5.5	Ω
On-Resistance Flatness	R _{FLATNESS}	$I_S = 1 \text{ mA}, V_D = -3 \text{ V}, 0 \text{ V}, +3 \text{ V}$	Room Full	25		40 60		40 55	
Switch Off	I _{S(off)}	V + = 5.5 V, $V - = -5.5 VV_D = + 4.5 V/-4.5 V$	Room Full	± 0.02	- 0.1 - 2	0.1 2	- 0.1 - 0.25	0.1 0.25	
Leakage Current	I _{D(off)}	$V_S = -4.5 \text{ V/+ } 4.5 \text{ V}$	Room Full	± 0.02	- 0.1 - 2	0.1 2	- 0.1 - 0.25	0.1 0.25	nA
Switch On Leakage Current	I _{D(on)}	V += 5.5 V, V -= -5.5 V $V_D = V_S = \pm 4.5 V$	Room Full	± 0.02	- 0.1 - 6	0.1 6	- 0.1 - 0.25	0.1 0.25	
Digital Control									L
Input Current, V _{IN} Low	I _{IL}	V _{IN} Under Test = 0.8 V	Full	0.005	- 0.1	0.1	- 0.1	0.1	
Input Current, V _{IN} High	I _{IH}	V _{IN} Under Test = 2 V	Full	0.005	- 0.1	0.1	- 0.1	0.1	μΑ
Input Capacitance ^e	e^{e} C_{IN} $f = 1 MHz$		Room	2					pF
Dynamic Characteristics									
Turn-On Time	t _{ON}	$R_L = 300 \ \Omega, C_L = 35 \ pF$	Room Full	27		55 90		55 75	
Turn-Off Time	t _{OFF}	$V_S = \pm 3 V$, see figure 1	Room Full	16		35 50		35 45	ns
Break-Before-Make Time Delay	t _{BBM}	DG613A only, $V_S = 3 V$ $R_L = 300 \Omega$, $C_L = 35 pF$	Room Full	15	2		2		
Charge Injection ^e	Q	$V_g = 0 \text{ V, R}_g = 0 \Omega, C_L = 1 \text{ nF}$	Room	1					рC
Off Isolation ^e	OIRR	B - 50 0 C - 5 pE	Room	- 62					
Channel-to-Channel Crosstalk ^e	X _{TALK}	$R_L = 50 \Omega$, $C_L = 5 pF$ f = 10 MHz	Room	- 90					dB
3 dB Bandwidth ^e	BW	$R_L = 50 \Omega, C_L = 5 pF$	Room	720					MHz
Source Off Capacitance ^e	C _{S(off)}	f = 1 MHz: V = 0 V	Room	2					
Drain Off Capacitance ^e	C _{D(off)}	$f = 1 \text{ MHz}; V_S = 0 \text{ V}$	Room	3					pF
		f = 1 MHz; V _S = V _D = 0 V	Room	9					
Drain On Capacitance ^e	OD(on)				1				
Drain On Capacitance ^e Total Harmonic Distortion ^e	C _{D(on)}	Signal = 1 V_{RMS} , 20 Hz to 20 kHz, R_L = 600 Ω	Room	0.01					%
Total Harmonic			Room	0.01					%
Total Harmonic Distortion ^e		R _L = 600 Ω	Room Full	0.01		0.1		0.1	%
Total Harmonic Distortion ^e Power Supplies	THD		Room		- 0.1 - 1		- 0.1 - 1		% μA



		Test Conditions Unless Otherwise Specified			- 40 °C t	o 125 °C	- 40 °C	to 85 °C	<u>:</u>
Parameter	Symbol	V + = + 5 V, V - = 0 V $V_{IN} = 2 V, 0.8 V^{a}$	Temp.b	Typ. ^c	Min. ^d	Max.d	Min. ^d	Max.d	Unit
Analog Switch		1 N = 1, 0.0 1	1.0	- 7 (-	1				J
Analog Signal Range ^e	V _{ANALOG}		Full		0	5	0	5	٧
On-Resistance	R _{ON}	V + = + 5 V, V - = 0 V $I_S = 1 mA, V_D = + 3.5 V$	Room Full	139		180 235		180 215	
On-Resistance Match	ΔR _{ON}	V + = + 5 V, V - = 0 V, $I_S = 1 mA, V_D = + 3.5 V$	Room Full	1		6 10		6 9	Ω
On-Resistance Flatness	R _{FLATNESS}	V + = + 5 V, V - = 0 V, $I_S = 1 \text{ mA}, V_D = 0 V, + 3.5 V$	Room Full	56		80 120		80 110	
Switch Off	I _{S(off)}	V + = 5.5 V, V - = 0 V V _D = 4.5 V/1 V	Room Full	± 0.02	- 0.1 - 2	0.1 2	- 0.1 - 0.25	0.1 0.25	
Leakage Current	I _{D(off)}	$V_S = 1 \text{ V}/4.5 \text{ V}$	Room Full	± 0.02	- 0.1 - 2	0.1 2	- 0.1 - 0.25	0.1 0.25	nA
Switch On Leakage Current	I _{D(on)}	V += 5.5 V, V -= 0 V $V_D = V_S = 1 V/4.5 V$	Room Full	± 0.02	- 0.1 - 6	0.1 6	- 0.1 - 0.25	0.1 0.25	
Digital Control			•			ı		ı	
Input Current, V _{IN} Low	I _{IL}	V _{IN} Under Test = 0.8 V	Full	0.005	- 0.1	0.1	- 0.1	0.1	μΑ
Input Current, V _{IN} High	I _{IH}	V _{IN} Under Test = 2 V	Full	0.005	- 0.1	0.1	- 0.1	0.1	μΛ
Input Capacitance ^e	C _{IN}	f = 1 MHz	Room	2					pF
Dynamic Characteristics	3								
Turn-On Time ^e	t _{ON}	$R_L = 300 \ \Omega, \ C_L = 35 \ pF$	Room Full	33		60 100		60 90	
Turn-Off Time ^e	t _{OFF}	$V_S = 3 V$, see figure 1	Room Full	16		35 50		35 45	ns
Break-Before-Make ^e Time Delay	t _{BBM}	DG613A only, $V_S = 3 V$ $R_L = 300 \Omega$, $C_L = 35 pF$	Room Full	19	2		2		
Charge Injection ^e	Q	$V_g = 0 \text{ V, } R_g = 0 \Omega, C_L = 1 \text{ nF}$	Full	2.3					рC
Off Isolation ^e	OIRR	$R_L = 50 \Omega, C_L = 5 pF$	Room	- 61					
Channel-to-Channel Crosstalk ^e	X _{TALK}	f = 10 MHz	Room	- 90					dB
3 dB Bandwidth ^e	BW	$R_L = 50 \Omega$, $C_L = 5 pF$	Room	675					MHz
Source Off Capacitance ^e	C _{S(off)}	f = 1 MHz; V _S = 0 V	Room	3					
Drain Off Capacitance ^e	C _{D(off)}	1 – 1 WII 12, VS – 0 V	Room	5					pF
Drain On Capacitance ^e	C _{D(on)}	$f = 1 \text{ MHz}; V_S = V_D = 0 \text{ V}$	Room	9					<u> </u>
Power Supplies						1			
Power Supply Current	l+		Room Full	0.001		0.1 1		0.1 1	
Negative Supply Current	I-	$V_{IN} = 0 V \text{ or } 5 V$	Room Full	- 0.001	- 0.1 - 1		- 0.1 - 1		μΑ
Ground Current	I _{GND}		Room Full	- 0.001	- 0.1 - 1		- 0.1 - 1		

DG611A, DG612A, DG613A

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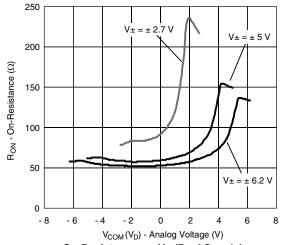


SPECIFICATIONS I	OR UNIP	OLAR SUPPLIES (V +	= + 3 V,	V - = 0	V)				
		Test Conditions Unless Otherwise Specified			- 40 °C t	o 125 °C	- 40 °C	to 85 °C	
Parameter	Symbol	V+ = + 3 V, V- = 0 V V _{IN} = 1.4 V, 0.6 V ^a	Temp.b	Typ. ^c	Min.d	Max.d	Min. ^d	Max. ^d	Unit
Analog Switch									
Analog Signal Range ^e	V _{ANALOG}		Full		0	3	0	3	V
On-Resistance	R _{ON}	$I_S = 1 \text{ mA}, V_D = + 1.5 \text{ V}$	Room Full	195		235 300		235 280	Ω
Switch Off	I _{S(off)}	V += 3.3 V, V-= 0 V $V_D = 3 \text{ V}/0.3 \text{ V}$	Room Full	± 0.02	- 0.1 - 2	0.1 2	- 0.1 - 0.25	0.1 0.25	
Leakage Current	I _{D(off)}	V _S = 0.3 V/3 V	Room Full	± 0.02	- 0.1 - 2	0.1 2	- 0.1 - 0.25	0.1 0.25	nA
Switch On Leakage Current	I _{D(on)}	V += 3.3 V, V-= 0 V $V_D = V_S = 0.3 V/3 V$	Room Full	± 0.02	- 0.1 - 6	0.1 6	- 0.1 - 0.25	0.1 0.25	
Digital Control			•		•	•		•	
Input Current, V _{IN} Low	I _{IL}	V _{IN} Under Test = 0.6 V	Full	0.005	- 0.1	0.1	- 0.1	0.1	
Input Current, V _{IN} High	I _{IH}	V _{IN} Under Test = 1.4 V	Full	0.005	- 0.1	0.1	- 0.1	0.1	μΑ
Input Capacitance ^e	C _{IN}	f = 1 MHz	Room	2					pF
Dynamic Characteristics	1					•		•	
Turn-On Time	t _{ON}	$R_L = 300 \Omega$, $C_L = 35 pF$	Room Full	87		125 180		125 170	
Turn-Off Time	t _{OFF}	V _S = 2 V, see figure 1	Room Full	33		55 65		55 60	ns
Break-Before-Make Time Delay	t _{BBM}	DG613 only, $V_S = 2 V$ $R_L = 300 \Omega$, $C_L = 35 pF$	Room Full	60	10		10		
Charge Injection ^e	Q	$V_g = 0 \text{ V}, R_g = 0 \Omega, C_L = 1 \text{ nF}$	Room	2.3					рC
Off Isolation ^e	OIRR	$R_L = 50 \Omega, C_L = 5 pF$	Room	- 60					
Channel-to-Channel Crosstalk ^e	X _{TALK}	f = 10 MHz	Room	- 90					dB
3 dB Bandwidth ^e	BW	$R_L = 50 \Omega, C_L = 5 pF$	Room	550					MHz
Source Off Capacitance ^e	C _{S(off)}	f 1MIV 0V	Room	5					
Drain Off Capacitance ^e	C _{D(off)}	$f = 1 \text{ MHz}; V_S = 0 \text{ V}$	Room	6					pF
Drain On Capacitance ^e	C _{D(on)}	$f = 1 \text{ MHz}; V_S = V_D = 0 \text{ V}$	Room	9					
Power Supplies									
Power Supply Current	l+		Room Full	0.001		0.1 1		0.1 1	
Negative Supply Current	l-	V _{IN} = 0 V or 3 V	Room Full	- 0.001	- 0.1 - 1		- 0.1 - 1		μΑ
Ground Current	I _{GND}		Room Full	- 0.001	- 0.1 - 1		- 0.1 - 1		

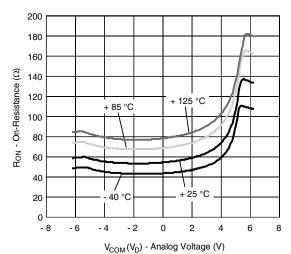
- a. V_{IN} = input voltage to perform proper function.
- b. Room = 25 °C, Full = as determined by the operating temperature suffix.
- c. Typical values are for DESIGN AID ONLY, not guaranteed nor subject to production testing.
- d. The algebraic convention whereby the most negative value is a minimum and the most positive a maximum, is used in this data sheet.
- e. Guaranteed by design, not subject to production test.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

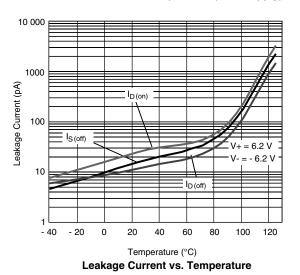
TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



On-Resistance vs. V_D (Dual Supply)



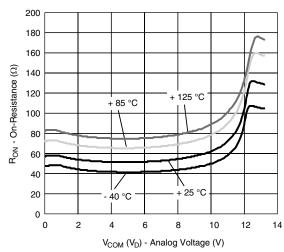
On-Resistance vs. Temperature (Dual Supply)



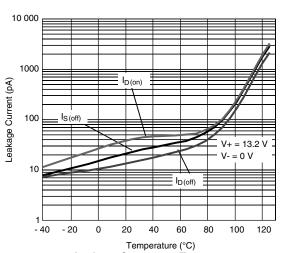
600 V+ = 2.7 V 500 V+ = 3 V V+ = 3 V V+ = 5 V V+ = 13.2 V 100 0 2 4 6 8 10 12 14

V_{COM} (V_D) - Analog Voltage (V)

On-Resistance vs. V_D (Single Supply)



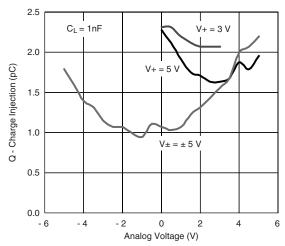
On-Resistance vs. Temperature (Single Supply)



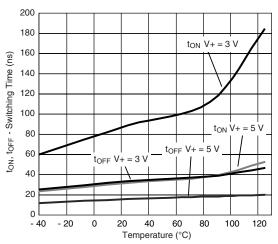
Leakage Current vs. Temperature

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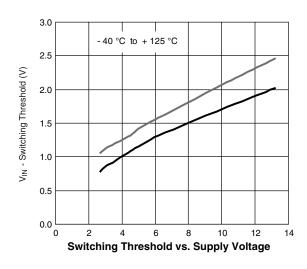
TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)

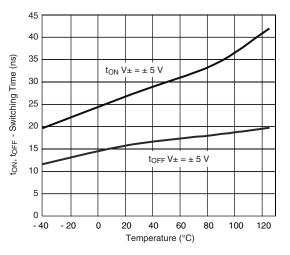


Charge Injection vs. Analog Voltage

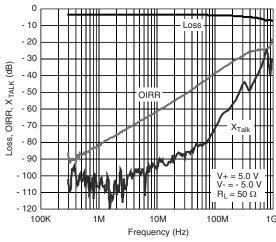


Switching Time vs. Temperature (Single Supply)

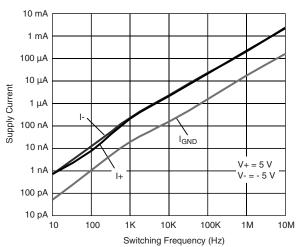




Switching Time vs. Temperature (Dual Supply)

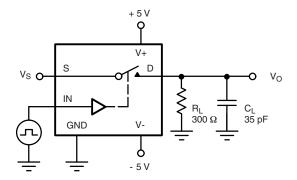


Insertion Loss, Off-Isolation, Crosstalk vs. Frequency



Supply Current vs. Switching Frequency

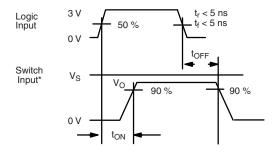
TEST CIRCUITS



C_L (includes fixture and stray capacitance)

$$V_O = V_S$$

$$\frac{R_L}{R_L + r_{DS(on)}}$$



Logic input waveform is inverted for switches that Note: have the opposite logic sense control

Figure 1. Switching Time

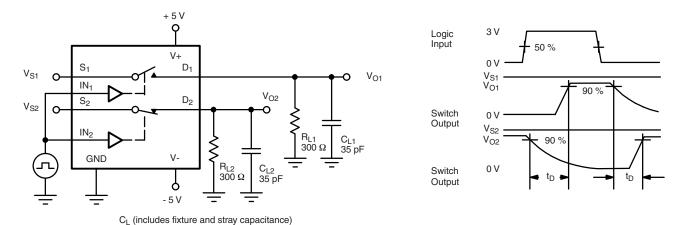


Figure 2. Break-Before-Make (DG613A)

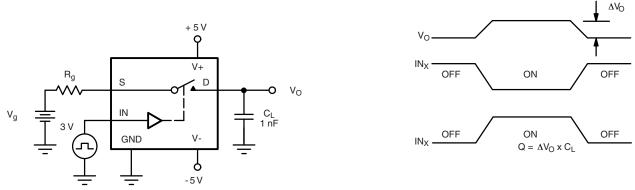


Figure 3. Charge Injection

TEST CIRCUITS



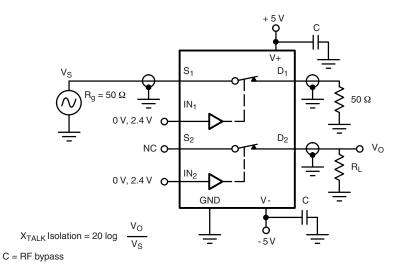


Figure 4. Crosstalk

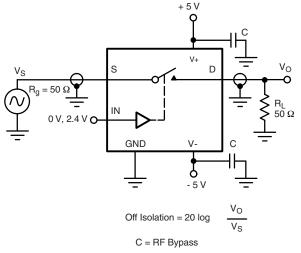


Figure 5. Off-Isolation

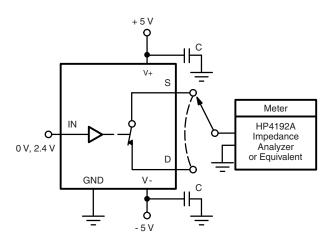
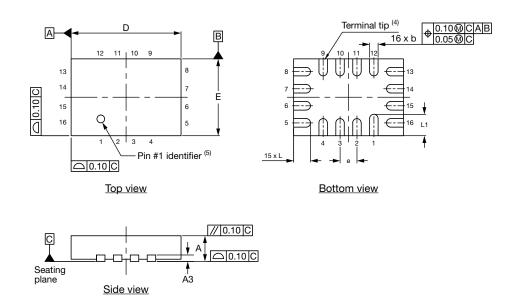


Figure 6. Source/Drain Capacitances

Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see www.vishay.com/ppg?69904.



Thin miniQFN16 Case Outline



DIMENSIONS		MILLIMETERS (1)			INCHES		
DIMENSIONS	MIN.	NOM.	MAX.	MIN.	NOM.	MAX.	
А	0.50	0.55	0.60	0.020	0.022	0.024	
A1	0	-	0.05	0	-	0.002	
A3		0.15 ref.			0.006 ref.		
b	0.15	0.20	0.25	0.006	0.008	0.010	
D	2.50	2.60	2.70	0.098	0.102	0.106	
е		0.40 BSC	0.40 BSC 0.016 BSC		0.016 BSC		
E	1.70	1.80	1.90	0.067	0.071	0.075	
L	0.35	0.40	0.45	0.014	0.016	0.018	
L1	0.45	0.50	0.55	0.018	0.020	0.022	
N (3)		16		16			
Nd ⁽³⁾		4		4			
Ne ⁽³⁾		4		4			

Notes

- (1) Use millimeters as the primary measurement.
- (2) Dimensioning and tolerances conform to ASME Y14.5M. 1994.
- (3) N is the number of terminals. Nd and Ne is the number of terminals in each D and E site respectively.
- (4) Dimensions b applies to plated terminal and is measured between 0.15 mm and 0.30 mm from terminal tip.
- (5) The pin 1 identifier must be existed on the top surface of the package by using identification mark or other feature of package body.
- (6) Package warpage max. 0.05 mm.

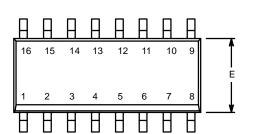
ECN: T16-0226-Rev. B, 09-May-16

DWG: 6023





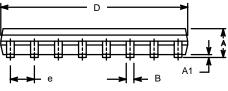
SOIC (NARROW): 16-LEAD JEDEC Part Number: MS-012

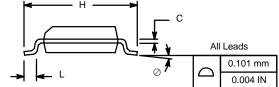


	MILLIN	IETERS	INCHES		
Dim	Min	Max	Min	Max	
Α	1.35	1.75	0.053	0.069	
A ₁	0.10	0.20	0.004	0.008	
В	0.38	0.51	0.015	0.020	
С	0.18	0.23	0.007	0.009	
D	9.80	10.00	0.385	0.393	
E	3.80	4.00	0.149	0.157	
е	1.27	BSC	0.050	BSC	
Н	5.80	6.20	0.228	0.244	
L	0.50	0.93	0.020	0.037	
0	0°	8°	0°	8°	
ECNI CO	2046 Day F	00 1.1.04			

ECN: S-03946-Rev. F, 09-Jul-01

DWG: 5300

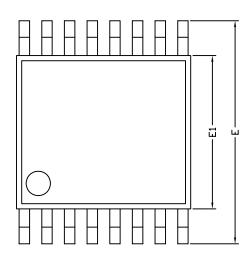


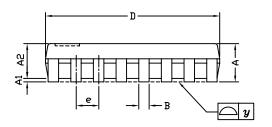


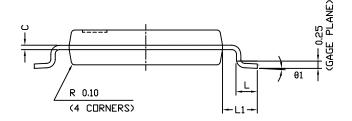
www.vishay.com 02-Jul-01



TSSOP: 16-LEAD







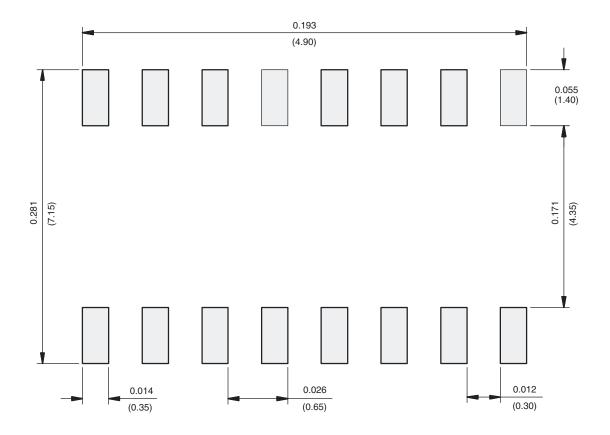
	DIMENSIONS IN MILLIMETERS						
Symbols	Min	Nom	Max				
А	-	1.10	1.20				
A1	0.05	0.10	0.15				
A2	-	1.00	1.05				
В	0.22	0.28	0.38				
С	-	0.127	-				
D	4.90	5.00	5.10				
E	6.10	6.40	6.70				
E1	4.30	4.40	4.50				
е	-	0.65	-				
L	0.50	0.60	0.70				
L1	0.90	1.00	1.10				
у	-	-	0.10				
θ1	0°	3°	6°				
FCN: S-61920-Rev. D. 23-	Oct-06						

DWG: 5624

Document Number: 74417 www.vishay.com 23-Oct-06



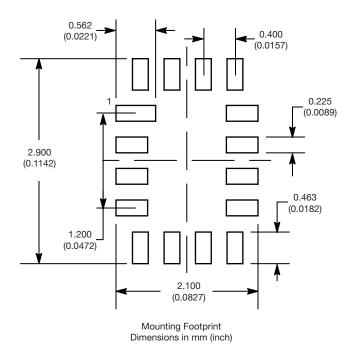
RECOMMENDED MINIMUM PAD FOR TSSOP-16



Recommended Minimum Pads Dimensions in inches (mm)

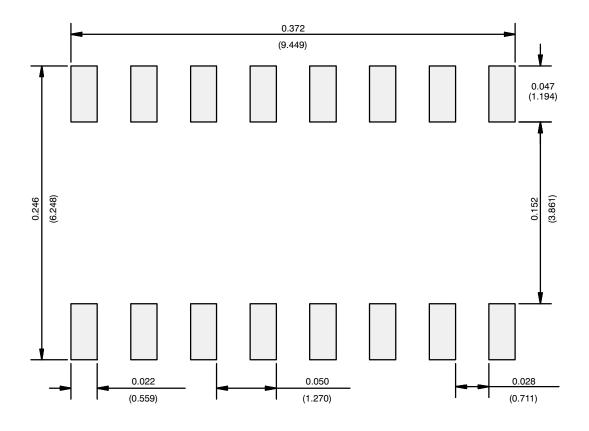


RECOMMENDED MINIMUM PADS FOR MINI QFN 16L





RECOMMENDED MINIMUM PADS FOR SO-16



Recommended Minimum Pads Dimensions in Inches/(mm)

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